

V _{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector current - Continuous	50	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

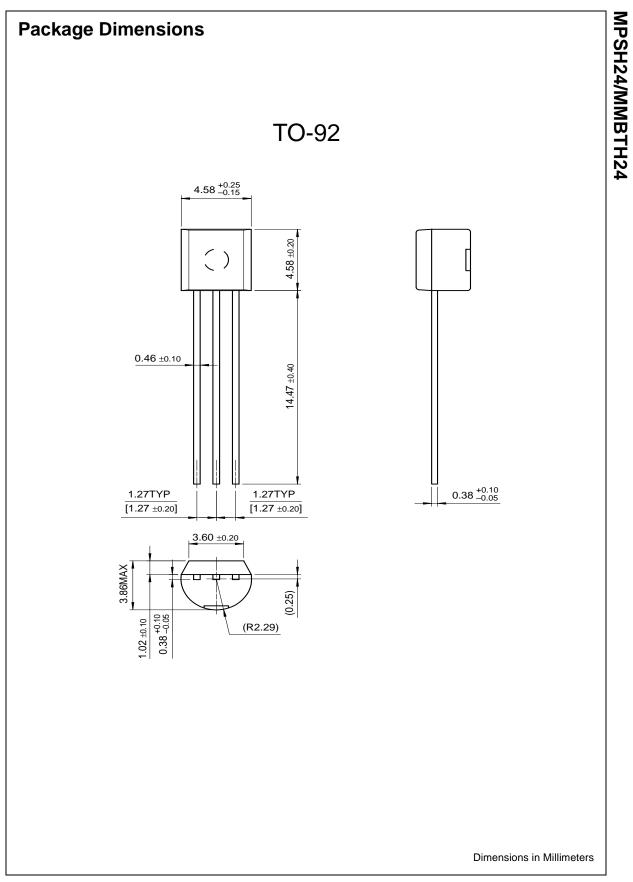
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	eristics					
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	30			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$	40			
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$	4.0			VV
I _{CBO}	Collector Cutoff Current	$V_{CB} = 15V, I_E = 0$			50	nA
On Characte	eristics					
h _{FE}	DC Current Gain	I _C = 8.0mA, V _{CE} = 10V	30			
Small Signa	I Characteristics					
f _T	Current Gain Bandwidth Product	I _C = 8.0mA, V _{CE} = 10V, f = 100MHz	400			MHz
C _{cb}	Collector-Base Capacitance	V _{CB} = 10V, I _E = 0, f = 1.0MHz			0.36	pF

se Width \leq 300µs, Duty Cycle \leq 2.0%

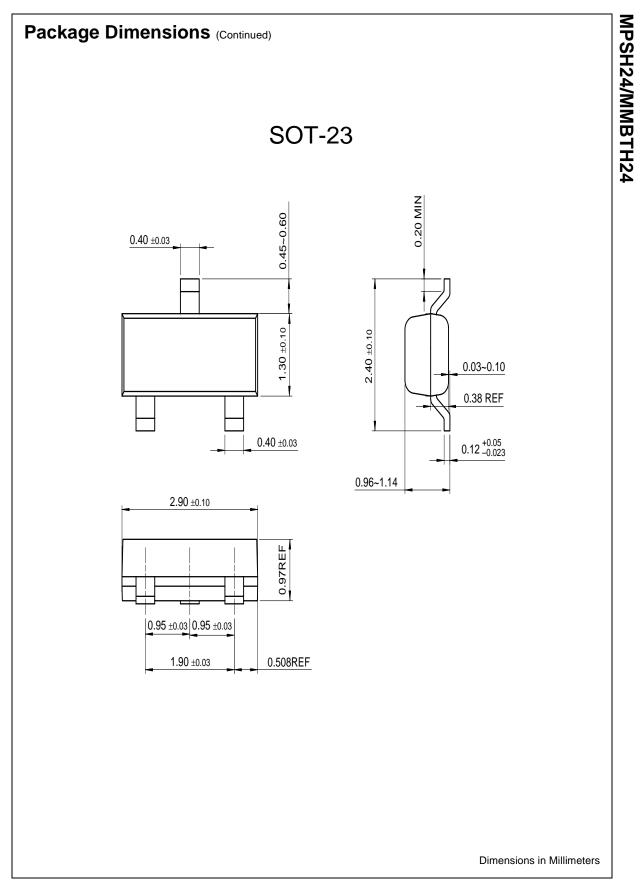
Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	M	Units	
		MPSH24	*MMBTH24	Units
P _D	Total Device Dissipation Derate above 25°C	625 5.0	225 1.8	mW mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	200	556	°C/W

* Device mounted on FR-4 PCB 1.6" \times 1.6" \times 0.06"



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